# 2SC3413

# Silicon NPN Epitaxial

# **HITACHI**

ADE-208-1085 (Z) 1st. Edition Mar. 2001

## Application

- Low frequency low noise amplifier
- HF amplifier

#### Outline

SPAK



- 1. Emitter
- 2. Collector
- 3. Base



## 2SC3413

## **Absolute Maximum Ratings** $(Ta = 25^{\circ}C)$

| Item                         | Symbol           | Ratings     | Unit |
|------------------------------|------------------|-------------|------|
| Collector to base voltage    | $V_{CBO}$        | 40          | V    |
| Collector to emitter voltage | V <sub>CEO</sub> | 30          | V    |
| Emitter to base voltage      | $V_{EBO}$        | 5           | V    |
| Collector current            | I <sub>c</sub>   | 100         | mA   |
| Collector power dissipation  | P <sub>c</sub>   | 300         | mW   |
| Junction temperature         | Tj               | 150         | °C   |
| Storage temperature          | Tstg             | -55 to +150 | °C   |

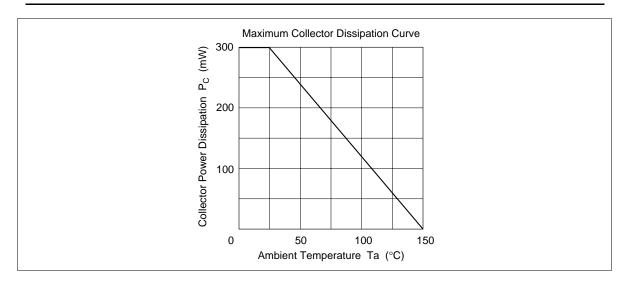
## Electrical Characteristics ( $Ta = 25^{\circ}C$ )

| Item                                    | Symbol               | Min | Тур | Max  | Unit | Test conditions  |
|---|----------------------|-----|-----|------|------|--|
| Collector to base breakdown voltage     | $V_{\text{(BR)CBO}}$ | 40  | _   | _    | V    | $I_{c} = 10 \ \mu A, \ I_{E} = 0$  |
| Collector to emitter breakdown voltage  | $V_{\text{(BR)CEO}}$ | 30  | _   | _    | V    | $I_C = 1 \text{ mA}, R_{BE} = \infty$  |
| Emitter to base breakdown voltage       | $V_{(BR)EBO}$        | 5   | _   | _    | V    | $I_{E} = 10  \mu A,  I_{C} = 0$  |
| Collector cutoff current                | I <sub>CBO</sub>     | _   | _   | 0.5  | μΑ   | $V_{CB} = 18 \text{ V}, I_{E} = 0$   |
| Emitter cutoff current                  | I <sub>EBO</sub>     | _   | _   | 0.5  | μΑ   | $V_{EB} = 2 \text{ V}, I_{C} = 0$  |
| DC current transfer ratio               | h <sub>FE</sub> *1   | 100 | _   | 500  |      | $V_{CE} = 12 \text{ V}, I_{C} = 2 \text{ mA}$  |
| Base to emitter voltage                 | V <sub>BE</sub>      | _   | _   | 0.75 | V    | $V_{CE} = 12 \text{ V}, I_{C} = 2 \text{ mA}$  |
| Collector to emitter saturation voltage | $V_{\text{CE(sat)}}$ | _   | _   | 0.2  | V    | $I_{\rm C} = 10 \text{ mA}, I_{\rm B} = 1 \text{ mA}$  |
| Gain bandwidth product                  | f <sub>T</sub>       | _   | 200 | _    | MHz  | $V_{CE} = 12 \text{ V}, I_{C} = 2 \text{ mA}$  |
| Collector output capacitance            | Cob                  | _   | _   | 3.5  | pF   | $V_{CB} = 10 \text{ V}, I_{E} = 0, f = 1 \text{ MHz}$  |
| Noise figure                            | NF                   | _   | 1.0 | 5.0  | dB   | $V_{CE} = 6 \text{ V}, I_{C} = 0.1 \text{ mA},$ $R_g = 1 \text{ k}\Omega, f = 1 \text{ kHz}$ |

Note: 1. The 2SC3413 is grouped by  $h_{\rm FE}$  as follows.

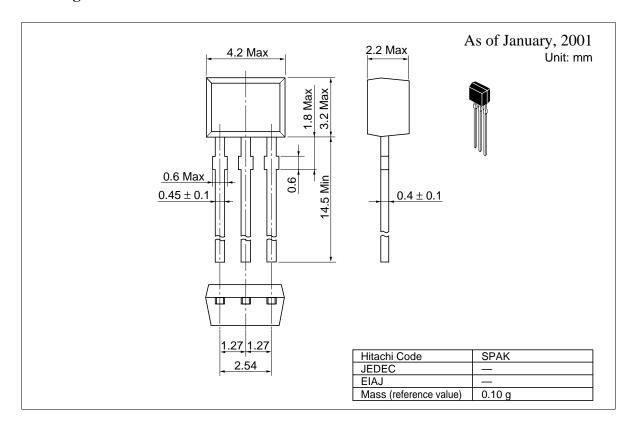
| В          | С          | D          |
|------------|------------|------------|
| 100 to 200 | 160 to 320 | 250 to 500 |

See characteristic curves of 2SC458(LG).



## 2SC3413

#### **Package Dimensions**



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